

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



NPN SILICON HIGH SPEED SWITHCHING TRANSISTOR



TO - 92 Plastic Package

LOW POWER AND HIGH SPEED SWITCHING APPLICATIONS

ABSOLUTE MAXIMUM RATINGS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter Voltage	V _{CEO}	15	V
Collector Base Voltage	V _{CBO}	40	V
Collector Emitter Voltage (V _{BE} =0)	V _{CES}	40	V
Emitter Base Voltage	V_{EBO}	4.5	V
Collector Current Peak	I _{CM}	500	mA
Power Dissipation @ Ta=25°C	P _D	625	mW
Operating And Storage Junction Temperature Range	T _j , T _{stg}	-65 to +200	°C

THERMAL RESISTANCE

Junction to Ambient in free air	$R_{th(j-a)}$	200	°C/W
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ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

CVMPOL	TEST CONDITION	VALUE		UNIT
STWIBOL	TEST CONDITION	MIN	MAX	ONLI
BV _{CEO (sus)} *	$I_C=10$ mA, $I_B=0$	15		V
BV _{CES}	$I_C=10\mu A, V_{BE}=0$	40		V
BV _{CBO}	$I_{C}=10\mu A, I_{E}=0$	40		V
BV _{EBO}	$I_E=10\mu A, I_C=0$	4.5		V
I _{CBO}	V _{CB} =20V, I _E =0 Ta=150°C		30	μΑ
I _{CES}	$V_{CE}=20V, V_{BE}=0$		0.4	μΑ
I _B	$V_{CE}=20V, V_{BE}=0$		0.4	μΑ
V _{CE(sat)} *	I _C =10mA, I _B =1mA		0.20	V
	I_C =30mA, I_B =3mA		0.25	V
	I _C =100mA, I _B =10mA		0.5	V
	I _C =10mA, I _B =1mA		0.3	V
	BV _{CES} BV _{CBO} BV _{EBO} I _{CBO} I _{CES}	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$



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ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	VALUE		UNIT	
DESCRIPTION	STWIBUL	TEST CONDITION	MIN	MAX	ONLI	
Base Emitter Saturation Voltage	V _{BE(sat)} *	I _C =10mA, I _B =1mA	0.7	0.85	V	
		I _C =30mA, I _B =3mA		0.15	V	
		I _C =100mA, I _B =10mA		1.60	V	
		I _C =10mA, I _B =1mA	0.59		V	
		Ta=+125°C	0.59		V	
		I _C =10mA, I _B =1mA		1.02	V	
		Ta= -55°C		1.02	V	
DC Current Gain	h _{FE} *	I _C =10mA, V _{CE} =1V	40	120		
		I _C =10mA, V _{CE} =1V	20			
		Ta= -55°C	20			
		I _C =30mA, V _{CE} =0.4V	30			
		I _C =100mA, V _{CE} =1V	20			
		I _C =10mA, V _{CE} =0.35v	40	120		

DYNAMIC CHARACTERISTICS

Output Capacitance	C_{ob} I_{E} =0, V_{CB} =5 V_{f} =140KHz			4	pF
Transition Frequency	f _T	V _{CE} =10V,I _C =10mA f=100MH _z	500		MHz

SWITCHING CHARCTERISTICS

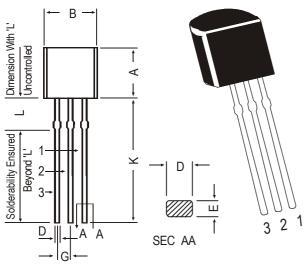
Turn on Time	t _{on}	I _C =10mA, I _{B1} =3mA, I _{B2} =1.5mA, V _{CC} =3V	12	ns
Turn off Time	t _{off}	I_{C} =10mA, I_{B1} =3mA, V_{CC} =3V, I_{B2} =1.5mA	15	ns
Storage Time		I _C =100mA, I _{B1} =10mA, I _{B2} = 10mA, V _{CC} =10V	13	ns

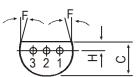
*Pulse Condition: Width \leq 300ms, Duty Cycle \leq 2%.

TO - 92 **Plastic Package**

TO-92 Plastic Package

TO-92 Transistors in Tape and Ammo Pack





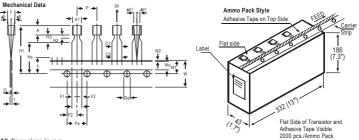
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PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

S	EC AA	<u></u>	3 2 1
	DIM	MIN.	MAX.
	Α	4.32	5.33
	В	4.45	5.20
	С	3.18	4.19
	D	0.41	0.55
	Е	0.35	0.50
	F	5 DI	EG
	G	1.14	1.40
	Н	1.14	1.53
	K	12.70	_
	L	1.982	2.082
	All dimir	sions in mi	m

All diminsions in mm.



		SPECIFICATION		ION	
SYMBOL	MIN.	NOM.	MAX.	TOL.	REMARKS
A1	4.0		4.8		
A	4.8		5.2		
T	3.9		4.2		
Р		12.7		± 1.0	
Po		12.7		± 0.3	CUMULATIVE PITCH ERROR 1.0 mm/20 PITCH
P2		6.35		± 0.4	TO BE MEASURED AT BOTTOM OF CLINCH
				0.0	
F		5.08			
∆h		0	1.0	- 0.2	AT TOP OF BODY
		0	1.3		AT TOP OF BODY
l w		18		± 0.5	
Wo		6		± 0.2	
W1		9		+ 0.7	
				- 0.5	
W2		0.5		± 0.2	
Но		16		± 0.5	
H1			23.25		
L			11.0		
Do		4		± 0.2	
t			1.2		t1 0.3-0.6
F1, F2		2.54		+ 0.4	
H2	0.45		1 45	- 0.1	
	0.40				
1	6N		0.22		
	A T P Po Po P2 F Δhh Δh1 W Wo W1 U2 Ho L Do t	MIN. A1 4.0 A 4.8 T 3.9 P P P P P P P P P P P P P P P P P P P	SYMBOL MIN. NOM. A1	SYMBOL MIN. NOM. MAX. A1 4.0 4.8 5.2 T 3.9 12.7 Po 12.7 12.7 P2 6.35 F Δh 0 1.0 Δh 0 1.3 W 18 6 W1 9 9 W2 0.5 16 H0 16 23.25 L 4 1.2 F1,F2 4 1.2 F1,F2 0.45 1.45 H3 0.45 1.45 JC1-C2 0.22 0.22	SYMBOL MIN. NOM. MAX. TOL. A1 4.0 4.8 5.2 T 3.9 4.2 ±1.0 Po 12.7 ±0.3 PZ 6.35 ±0.4 F 5.08 +0.6 Δh 0 1.0 Δh1 0 1.3 W 18 ±0.2 W1 9 +0.7 -0.5 ±0.2 H0 16 23.25 L 4 1.0 t 2.5 ±0.5 ±0.5 ±0.5 ±0.2 ±0.5 ±0.5 ±0.5 H1 ±0.5 ±0.5 t 11.0 ±0.5 t 1.2 ±0.5 F1,F2 4 1.2 F1,F2 0.45 1.45 H3 0.045 1.45 H3 0.22

- NOTES

 1. Maximum alignment deviation between leads will not to be greater than 0.2mm.

 2. Maximum non-cumulative variation between lape field holies shall not exceed 1 mm in 20 pitches.

 3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.

 4. There will be no more than three (3) consecutive missing components in a tape.

 5. A tape traitier, having at least three feed holes are provided after the last component in a tape.

 6. Splices should not interfere with the sprocket feed holes.

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details Net Weight / Qty S		Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

Notes P2N2369A

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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